

MOS FIELD EFFECT TRANSISTOR 2SK3056

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

This product is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Low On-State Resistance $R_{DS(on)1} = 34 \text{ m}\Omega \text{ MAX.}$ (VGs = 10 V, ID = 16 A) $R_{DS(on)2} = 50 \text{ m}\Omega \text{ MAX.}$ (VGs = 4.0 V, ID = 16 A)
- Low Ciss : Ciss = 920 pF TYP.
- Built-in Gate Protection Diode

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage (Vgs = 0 V)	Vdss	60	V
Gate to Source Voltage (VDS = 0 V)	VGSS(AC)	±20	V
Gate to Source Voltage (VDS = 0 V)	VGSS(DC)	+20, -10	V
Drain Current (DC)	ID(DC)	±32	Α
Drain Current (Pulse) Note1	D(pulse)	±100	А
Total Power Dissipation (Tc = 25°C)	Рт	34	W
Total Power Dissipation (TA = 25°C)	Рт	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	16	А
Single Avalanche Energy Note2	Eas	25.6	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting Tch = 25 °C, RG = 25 Ω , VGS = 20 V \rightarrow 0 V

THERMAL RESISTANCE

Channel to Case	Rth(ch-C)	3.68	°C/W
Channel to Ambient	Rth(ch-A)	83.3	°C/W

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ORDERING INFORMATION

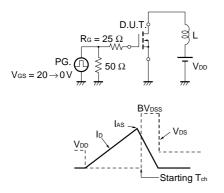
PART NUMBER	PACKAGE		
2SK3056	TO-220AB		
2SK3056-S	TO-262		
2SK3056-ZJ	TO-263		

NEC

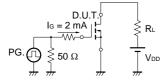
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

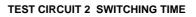
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 16 A		24	34	mΩ
	RDS(on)2	Vgs = 4.0 V, Id = 16 A		35	50	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	Vds = 10 V, Id = 1 mA	1.0	1.5	2.0	V
Forward Transfer Admittance	yfs	Vds = 10 V, Id = 16 A	8.0	20		S
Drain Leakage Current	IDSS	Vds = 60 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V _{DS} = 10 V		920		pF
Output Capacitance	Coss	Vgs = 0 V		280		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		120		pF
Turn-on Delay Time	td(on)	ID = 16 A		25		ns
Rise Time	tr	$V_{GS(on)} = 10 V$		300		ns
Turn-off Delay Time	td(off)	Vdd = 30 V		70		ns
Fall Time	tr	Rg = 10 Ω		120		ns
Total Gate Charge	QG	ID = 32 A		25		nC
Gate to Source Charge	Q _{GS}	Vdd = 48 V		3.3		nC
Gate to Drain Charge	Qgd	Vgs = 10 V		7.0		nC
Body Diode Forward Voltage	VF(S-D)	IF = 32 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	If = 32A, V _{GS} = 0 V		50		ns
Reverse Recovery Charge	Qrr	di/dt = 100A/µs		68		nC

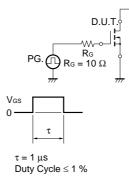
TEST CIRCUIT 1 AVALANCHE CAPABILITY

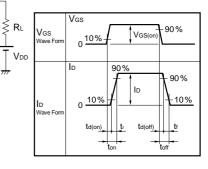


TEST CIRCUIT 3 GATE CHARGE

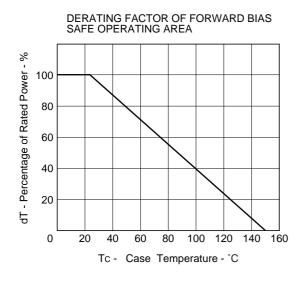




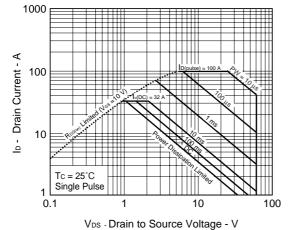




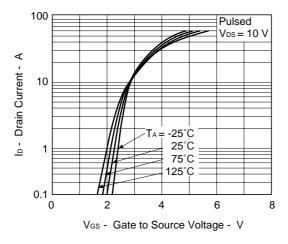
TYPICAL CHARACTERISTICS (TA = 25 °C)

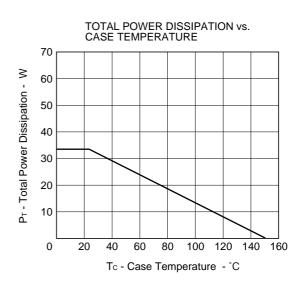




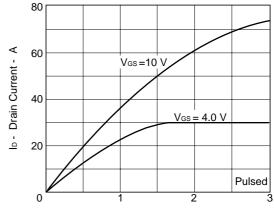


FORWARD TRANSFER CHARACTERISTICS

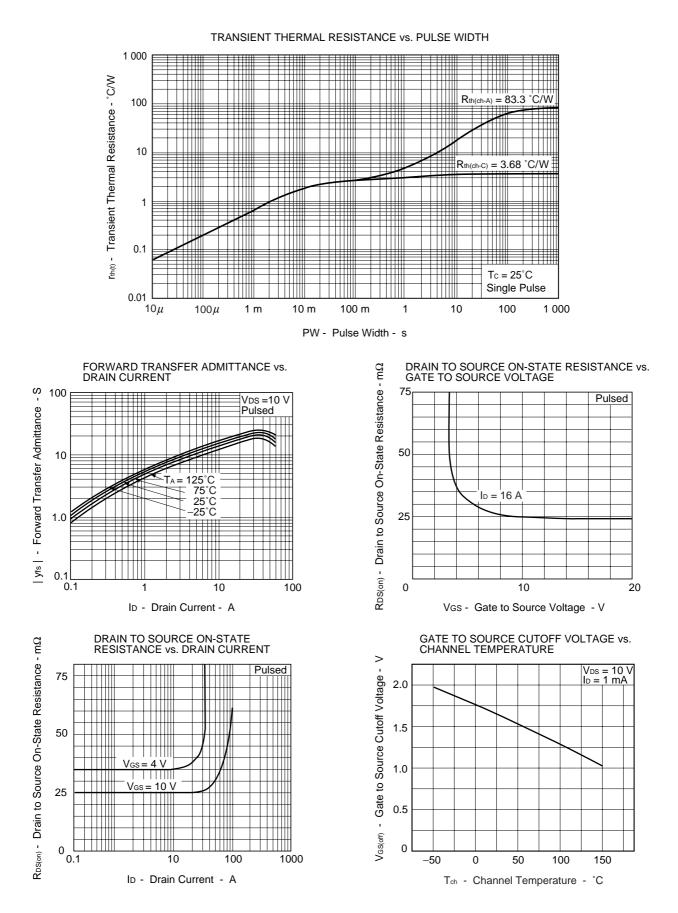


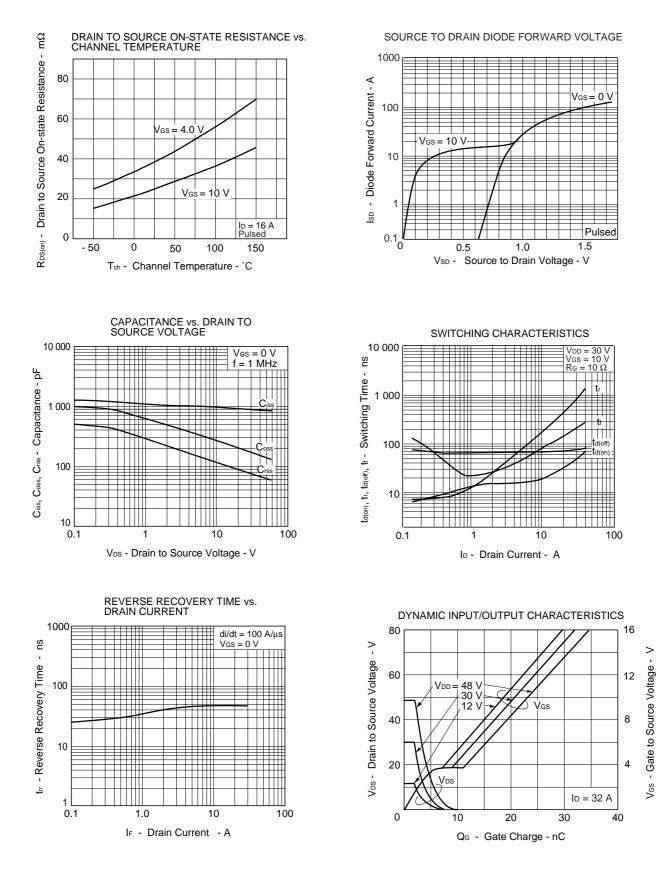




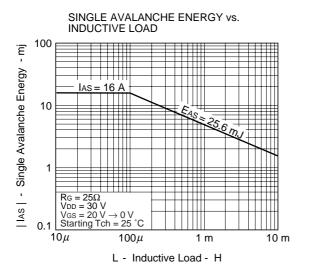


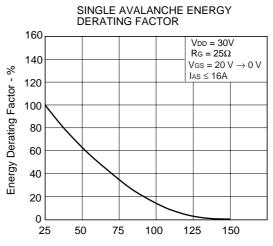
V_{DS} - Drain to Source Voltage - V





Data Sheet D13095EJ1V0DS00



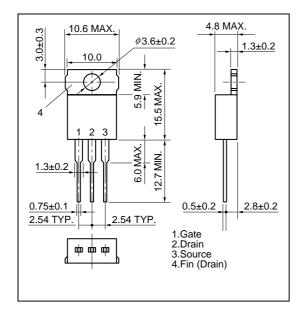


Starting Tch - Starting Channel Temperature - °C

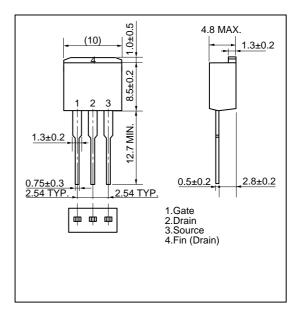
Data Sheet D13095EJ1V0DS00

PACKAGE DRAWINGS (Unit : mm)

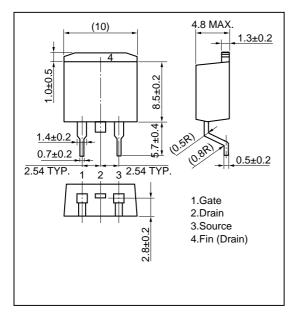
1)TO-220AB (MP-25)



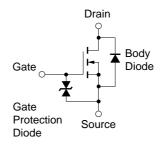
2)TO-262 (MP-25 Fin Cut)



3)TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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